

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

LDTC123YLT1G

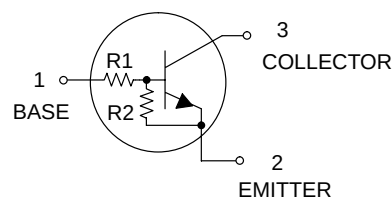
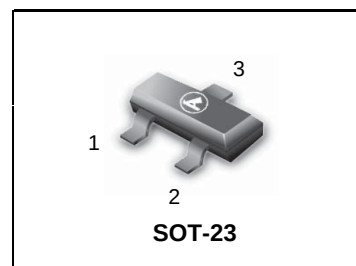
● Applications

Inverter, Interface, Driver

● Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

- We declare that the material of product compliance with RoHS requirements.



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V_{CC}	50	V
Input voltage	V_{IN}	-5 to +12	V
Output current	I_O	100	mA
	$I_{C(Max.)}$	100	
Power dissipation	P_d	200	mW
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTC123YLT1G	N8	2.2	10	3000/Tape & Reel
LDTC123YLT3G	N8	2.2	10	10000/Tape & Reel

● Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	0.3	V	$V_{CC}=5V, I_O=100\mu A$
	$V_{I(on)}$	3	—	—		$V_O=0.3V, I_O=20mA$
Output voltage	$V_{O(on)}$	—	0.1	0.3	V	$I_O/I_I=10mA/0.5mA$
Input current	I_I	—	—	3.8	mA	$V_I=5V$
Output current	$I_{O(off)}$	—	—	0.5	μA	$V_{CC}=50V, V_I=0V$
DC current gain	G_I	33	—	—	—	$V_O=5V, I_O=10mA$
Input resistance	R_1	1.54	2.2	2.86	k Ω	—
Resistance ratio	R_2/R_1	3.6	4.5	5.5	—	—
Transition frequency	f_T^*	—	250	—	MHz	$V_{CE}=10V, I_E=-5mA, f=100MHz$

* Characteristics of built-in transistor

LDT C123YLT1G

Electrical characteristic curves

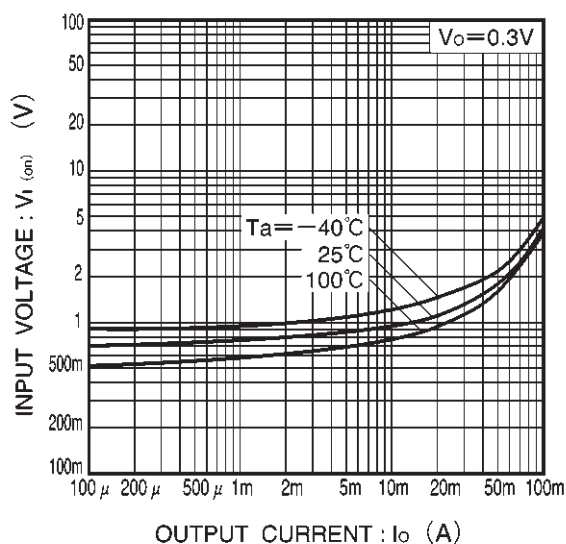


Fig.1 Input voltage vs. output current (ON characteristics)

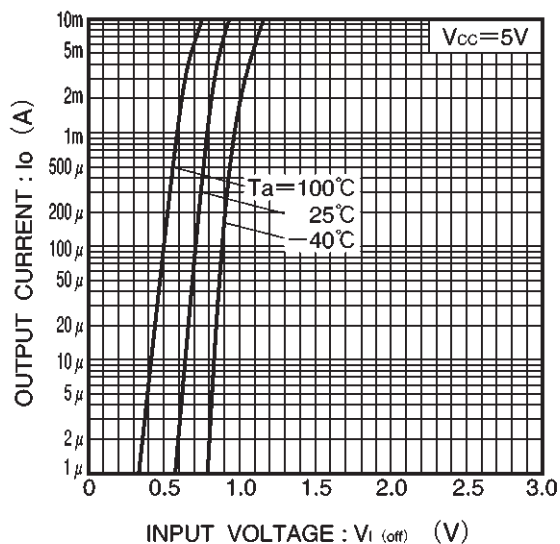


Fig.2 Output current vs. input voltage (OFF characteristics)

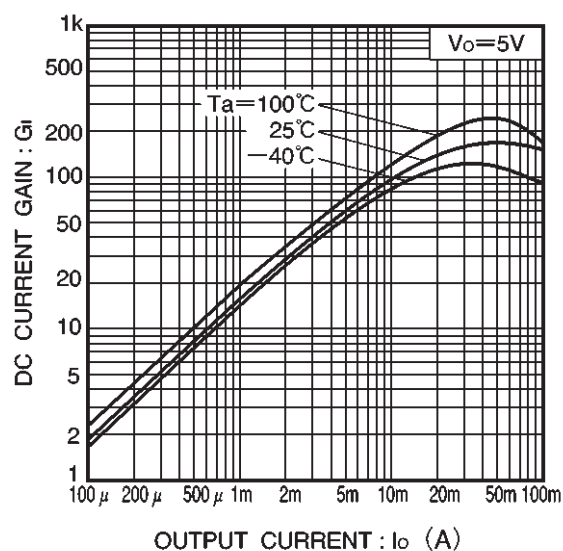


Fig.3 DC current gain vs. output current

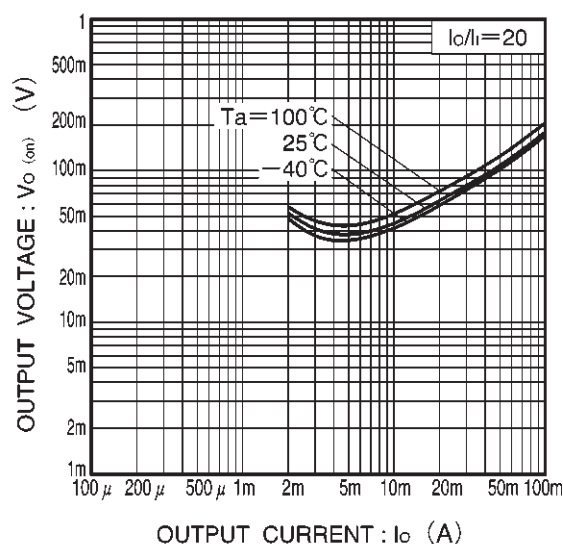
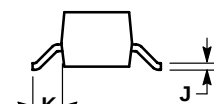
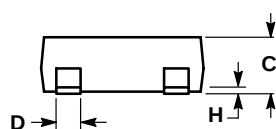
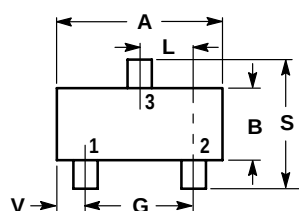


Fig.4 Output voltage vs. output current

LDTC123YLT1G
SOT-23
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
E	0.0701	0.0807	1.78	2.04
F	0.0005	0.0040	0.013	0.100
G	0.0034	0.0070	0.085	0.177
H	0.0140	0.0285	0.35	0.69
I	0.0350	0.0401	0.89	1.02
J	0.0830	0.1039	2.10	2.64
K	0.0177	0.0236	0.45	0.60

